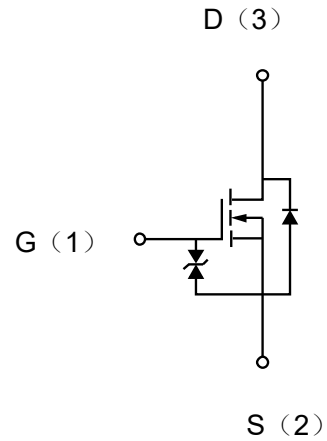


Description

The MOSFET provide the best combination of fast switching, low on-resistance and cost-effectiveness.

MOSFET Product Summary		
V _{DS} (V)	R _{DS(on)} (Ω)	I _D (A)
20	0.2@ V _{GS} =4.5V	1
	0.25@ V _{GS} =2.5V	
	0.31@ V _{GS} =1.8V	
ESD	HBM	MM
	Pass 500V	Pass 100V



Absolute maximum rating@25°C

Parameter	Symbol	Value	Units
Drain-Source Voltage	V _{DS}	20	V
Gate-Source Voltage	V _{GS}	±10	V
Continuous Drain Current(T _J =150°C)	Continuous	I _D	1
	Pulsed	I _{DP}	4
Total power dissipation	P _D	140	mW
Channel temperature	T _{CH}	150	°C
Range of storage temperature	T _{STG}	-55 to +150	°C

Thermal resistance

Parameter	Symbol	Limits	Units
Channel to ambient	R _{th(ch-a)}	800	°C/W

Electrical characteristics per line@25°C (unless otherwise specified)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Units
Drain-Source Breakdown Voltage	BV_{DSS}	$I_D = 1mA, V_{GS} = 0V$	20		-	V
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS} = 20V, V_{GS} = 0V$	-	-	1	μA
Gate-Body Leakage Current	I_{GSS}	$V_{DS} = 0V, V_{GS} = \pm 8V$	-	-	± 10	μA
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = 5V, I_D = 1mA$	0.5	-	1.0	V
Static Drain-Source On-Resistance	$R_{DS(on)}$	$V_{GS} = 4.5V, I_D = 650mA$	-	0.2	0.25	Ω
		$V_{GS} = 2.5V, I_D = 450mA$	-	0.25	0.3	Ω
		$V_{GS} = 1.8V, I_D = 250mA$		0.31	0.45	Ω
Forward transfer admittance	$ Y_{fs} $	$V_{DS} = 10V, I_D = 300mA$	395			ms
Input Capacitance	C_{iss}	$V_{GS} = 0V, V_{DS} = 10V,$ $f = 1MHz$	-	30		pF
Output Capacitance	C_{oss}		-	13		pF
Reverse Transfer Capacitance	C_{rss}		-	3		pF
Turn-On Delay Time	$t_{d(on)}$	$V_{DD} = 10V, V_{GS} = 4.0V,$ $R_G = 10\Omega, R_L = 67\Omega$ $I_D = 150mA$	-	7		ns
Turn-Off Delay Time	$t_{d(off)}$		-	23		ns
Turn-On Rise Time	t_r		-	15		ns
Turn-On Fall Time	t_f		-	15		ns
Drain-Source Diode Forward Voltage	V_{SD}	$V_{GS} = 0V, I_S = 100mA$		-	1.2	V
Total Gate Charge	Q_g	$V_{GS} = 4.5V, V_{DS} = 10V,$ $I_D = 0.55A$		0.54		nC
Gate-Source Charge	Q_{gs}			0.08		nC
Gate-Drain Charge	Q_{gd}			0.15		nC

Typical Characteristics

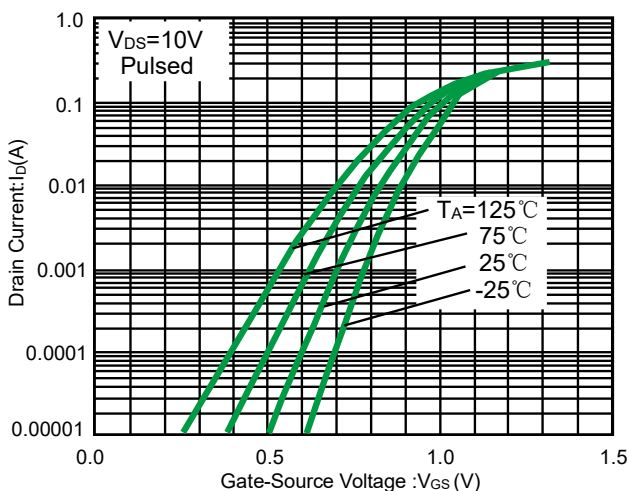


Fig 1. Typical transfer Characteristics

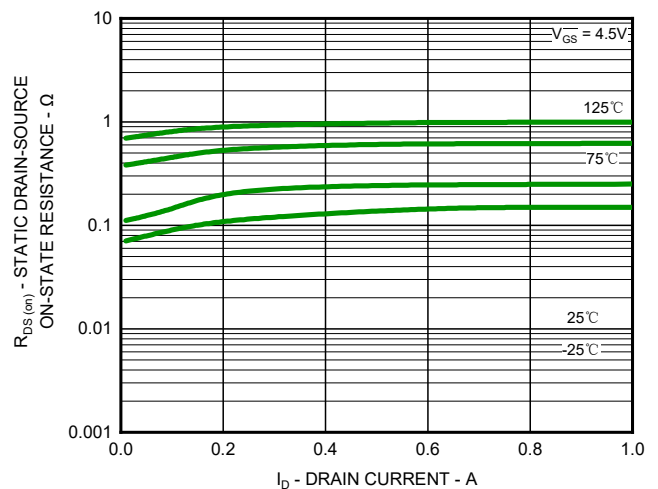


Fig 2. Static drain-source on-state resistance vs. drain current(I)

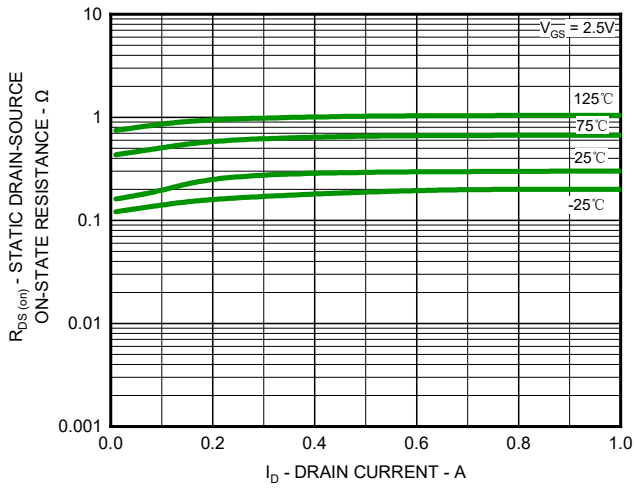


Fig 3. Static drain-source on-state resistance Vs. drain current (II)

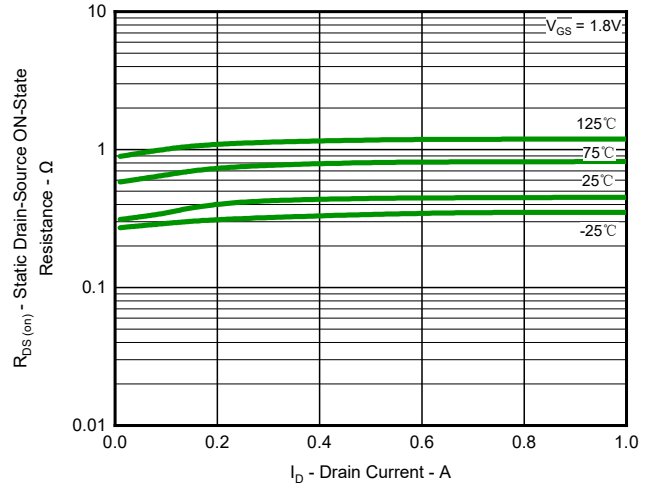


Fig 4. Static drain-source on-state resistance vs. drain current (III)

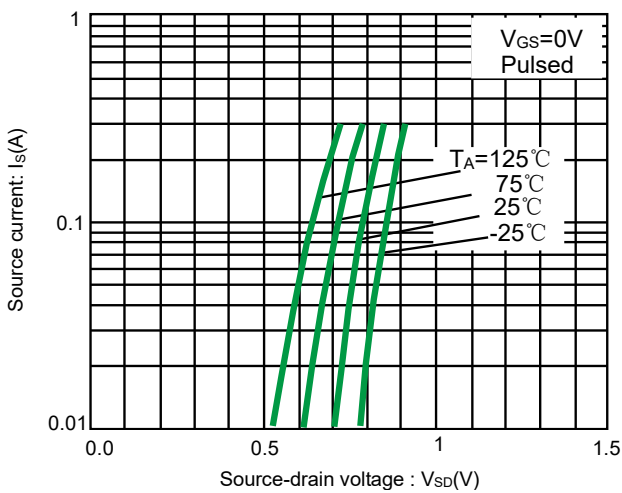


Fig 5. Source current vs. source-drain voltage

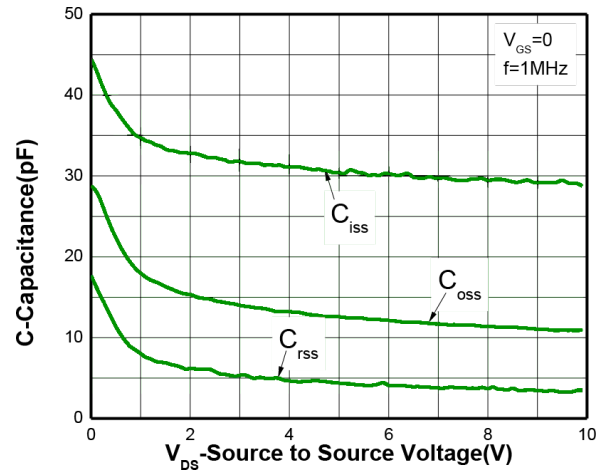


Fig 6. Typical capacitance vs. drain-source voltage

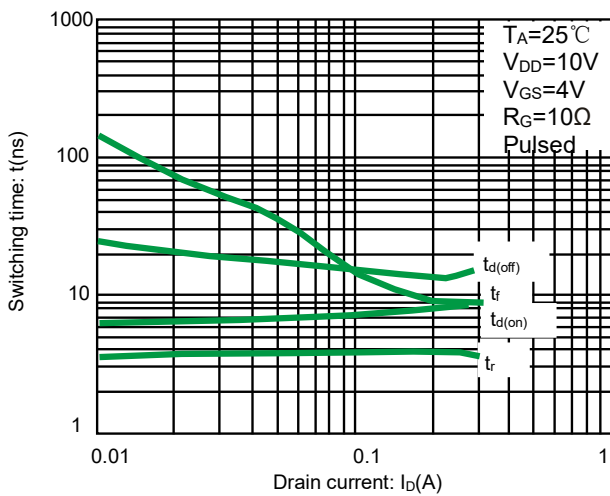


Fig 7. Switching characteristics

Switching characteristics measurement circuit

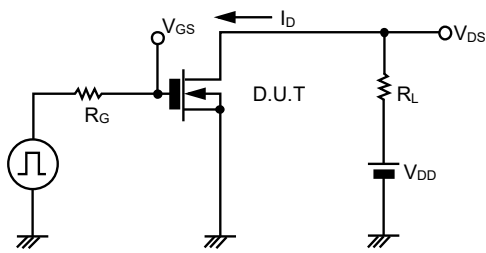


Fig.8 Switching time measurement circuit

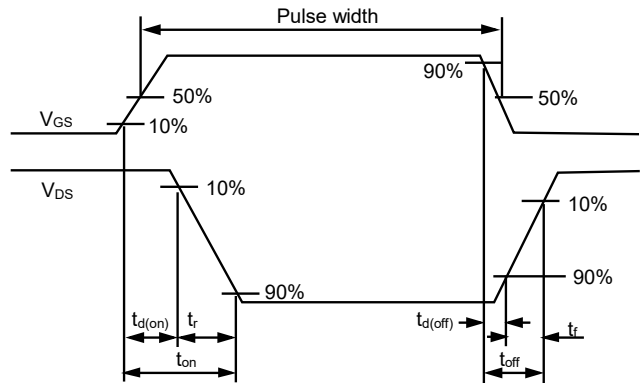
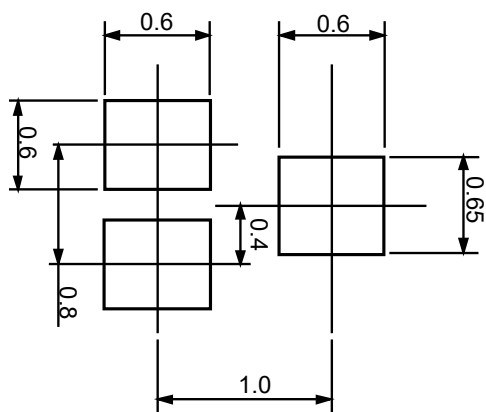
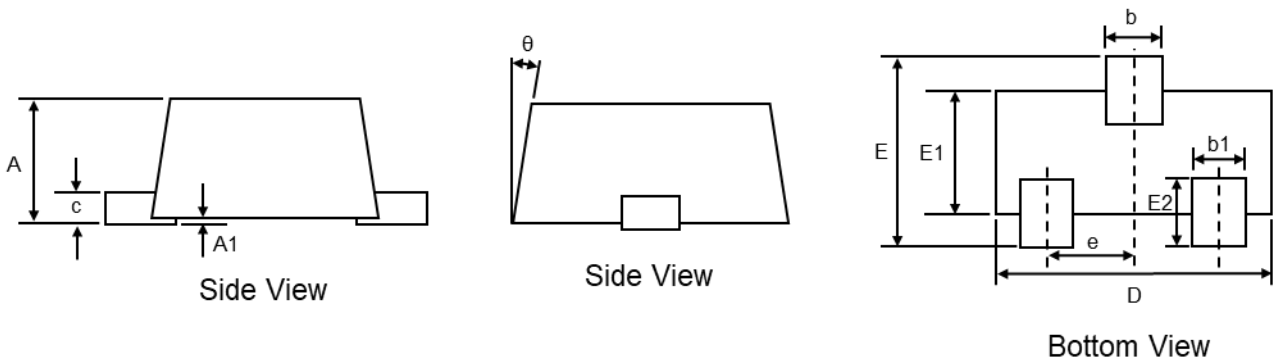


Fig.9 Switching time waveforms

Product dimension (SOT-723)



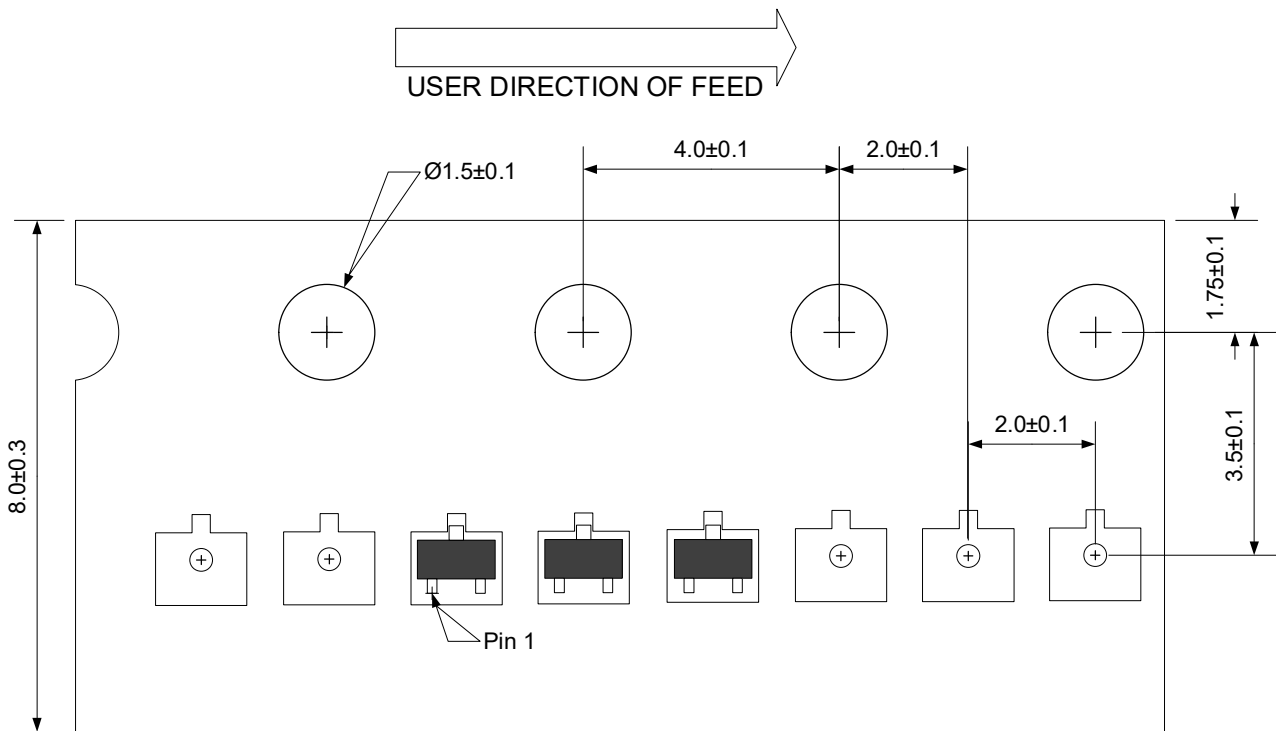
Unit: mm

Dim	Millimeters	
	Min	Max
A	0.40	0.55
A1	0.00	0.05
b	0.20	0.37
b1	0.15	0.27
c	0.06	0.18
D	1.10	1.30
E	1.10	1.30
E1	0.70	0.90
E2	0.20	0.30
e	0.40 Ref.	
θ	5°	9°

Ordering information

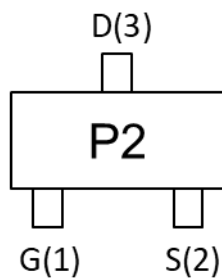
Device	Package	Shipping
PNM723T201E0	SOT-723 (Pb-Free)	10000 / Tape & Reel

Load with information




Unit:mm

Marking information




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